

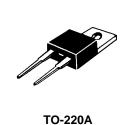
F08A30 Thru F08A60

Fast Recovery Power Rectifiers

Designed for use in switching power supplies. inverters and as free wheeling diodes. These state-of-the-art devices have the following features:

- $\ast\, {\rm Glass}$ Passivated chip junctions
- *Low Reverse Leakage Current
- * Fast Switching for High Efficiency
- $*150^{\circ}$ C Operating Junction Temperature
- *Low Forward Voltage , High Current Capability
- * Plastic Material used Carries Underwriters Laboratory
- *Flammability Classification 94V-O
- * Pb Free

* In compliance with EU RoHs directives

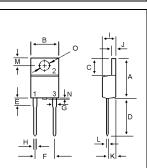


MAXIMUM RATINGS

Characteristic S	Symbol	F08A				Unit
		30	40	50	60	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{rrm} V _{rwm} V _r	300	400	500	600	V
RMS Reverse Voltage	V _{R(RMS)}	210	280	350	420	V
Average Rectifier Forward Current	I _{F(AV)}	8.0			A	
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I _{FSM}	100			A	
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150		°C		

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	F08A				Unit
		30	40	50	60	Unit
Maximum Instantaneous Forward Voltage ($I_F = 8.0 \text{ Amp } T_C = 25^{\circ}C$)	VF	1.30		1.5		V
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 100^{\circ}C$)	I _R	10 500		uA		
Reverse Recovery Time (I _F = 0.5 A, I _R =1.0,I _{rr} =0.25 A)	Trr	250		ns		
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	CP	70		₽F		

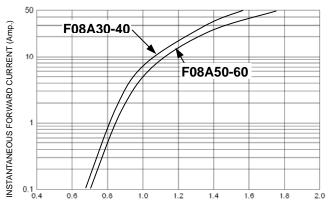


	DIM MILLIMETERS				
	DIN	MIN	MAX		
	Α	14.68	16.00		
	В	9.78	10.42		
	С	5.02	6.60		
	D	13.00	14.62		
	Е	3.10	4.19		
	F	2.41	2.67		
	G	1.10	1.67		
	Н	0.69	1.01		
	I	3.21	4.98		
	J	1.14	1.40		
	Κ	2.20	3.30		
	L	0.28	0.61		
	М	2.48	3.00		
	Ν		1.00		
	0	3.50	4.00		
¹⁰ ² Case Positive CASE Suffix "P"					
¹ 0 ² Case Negative ³ 0 ← CASE Suffix "R"					

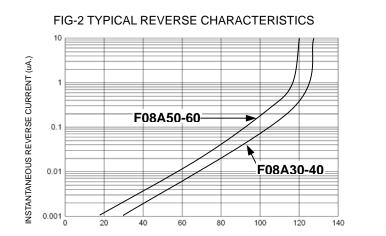


F08A30 Thru F08A60

FIG-1 TYPICAL FORWARD CHARACTERISTICS



FORWARD VOLTAGE (Volts)



PERCENT OF PEAK REVERSE VOLTAGE (%)



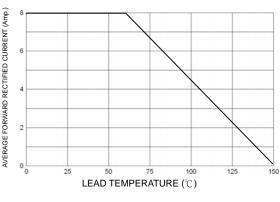


FIG-4TYPICAL JUNCTION CAPACITANCE

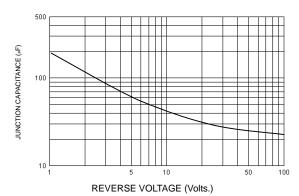
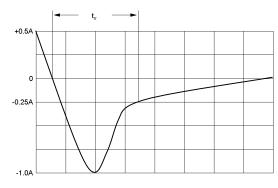
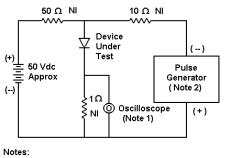


FIG-5PEAK FORWARD SURGE CURRENT







1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF 2. Rise Time = 10 ns max. Input Impedance = 50 Ω

Set time base for 50/100 ns/cm

FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram



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